

### **Description**

ACE2398M uses advanced trench technology to provide excellent R<sub>DS(ON)</sub>.

This device particularly suits for low voltage application such as power management of desktop computer or notebook computer power management, DC/DC converter.

#### **Features**

- Low r<sub>DS(on)</sub> trench technology
- Low thermal impedance
- Fast switching speed

## **Applications**

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

### **Absolute Maximum Ratings**

Parameter		Symbol	Limit	Units	
Drain-Source Voltage		$V_{DS}$	60	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C		2.2	А	
	T <sub>A</sub> =70°C	- I <sub>D</sub>	1.7		
Pulse Drain Current b		I <sub>DM</sub>	10	Α	
Continuous Source Current (Diode Conduction) a		Is	1.9	Α	
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	D	1.3	· W	
	T <sub>A</sub> =70°C	- P <sub>D</sub>	0.8		
Operating Temperature / Storage Temperature		T <sub>J</sub> /T <sub>STG</sub>	-55/150	°С	

<sup>\*1</sup> Pw  $\leq$ 10  $\mu$ s, Duty cycle  $\leq$ 1 %

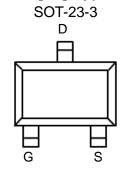
### THERMAL RESISTANCE RATINGS

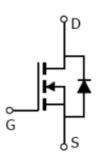
Parameter		Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	- R <sub>θJA</sub>	100	°C/W
	Steady State		166	C/VV

<sup>\*2</sup> When mounted on a 1\*0.75\*0.062 inch glass epoxy board%

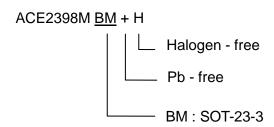


# **Packaging Type**





# **Ordering information**





### **Electrical Characteristics**

(T<sub>A</sub>=25°C, unless otherwise specified)

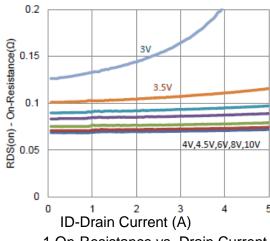
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit			
Static									
Gate-Source Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V			
Gate-Body Leakage	VGS(th)	$V_{DS} = 0 \text{ V}, \text{ VGS} = \pm 20 \text{ V}$			±100	uA			
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA			
		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25				
On-State Drain Current a	ID(on)	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	4			Α			
Drain-Source On-Resistance a	rDS(on)	$V_{GS} = 10 \text{ V}, I_{D} = 1.7 \text{ A}$			194	mΩ l			
		$V_{GS} = 4.5 \text{ V}, I_{D} = 1.4 \text{ A}$			273				
Forward Transconductance a	gfs	$V_{DS} = 15 \text{ V}, I_{D} = 1.7 \text{ A}$		18		S			
Diode Forward Voltage a	VSD	Is = 0.95 A, V <sub>G</sub> s = 0 V		0.74		V			
Dynamic b									
Total Gate Charge	Qg			3.7		nC			
Gate-Source Charge	Qgs	$V_{DS} = 30 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 1.7 \text{ A}$		0.9					
Gate-Drain Charge	Qgd			1.7					
Turn-On Delay Time	t <sub>d(on)</sub>			2		nS			
Rise Time	tr	$V_{DS} = 30 \text{ V}, R_L = 17.7 \Omega, I_D = 1.7 \text{ A},$		6					
Turn-Off Delay Time	t <sub>d(off)</sub> *	$V_{GEN}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		17					
Fall Time	t <sub>f</sub>			5					
Input Capacitance	C <sub>iss</sub>			330		pF			
Output Capacitance	C <sub>oss</sub>	VDS = 15 V, VGS = 0 V, f = 1 MHz		30					
Reverse Transfer Capacitance	C <sub>rss</sub>			27					

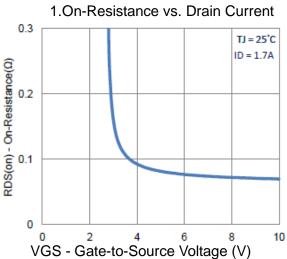
#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

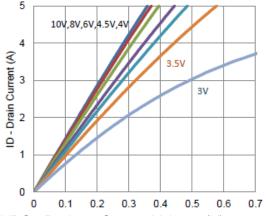


## **Typical Performance Characteristics**

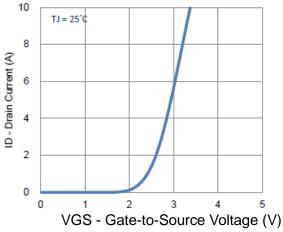




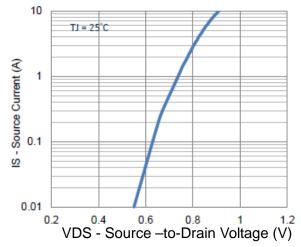
3. On-Resistance vs. Gate-to-Source Voltage



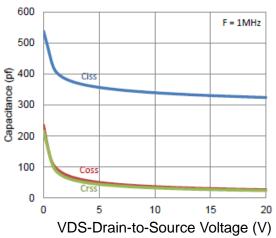
VDS - Drain-to-Source Voltage (V) 5. Output Characteristics



2. Transfer Characteristics



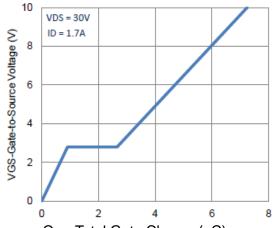
4. Drain-to-Source Forward Voltage



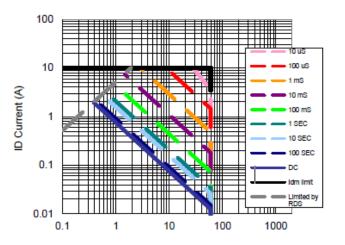
6. Capacitance



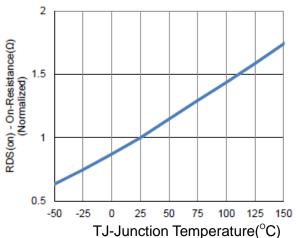
## **Typical Performance Characteristics**



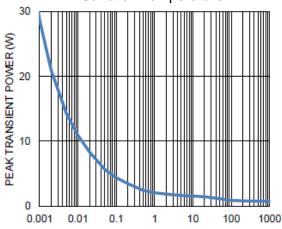
Qg - Total Gate Charge (nC) 7. Gate Charge



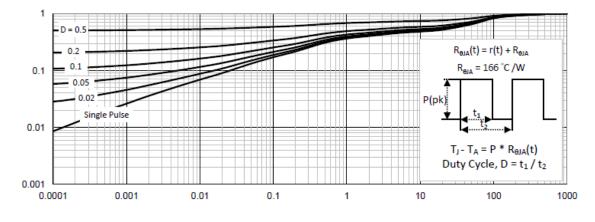
VDS Drain to Source Voltage (V) 9. Safe Operating Area



8. Normalized On-Resistance Vs
Junction Temperature



t1 TIME (sec)
10.Single Pulse Maximum Power Dissipation



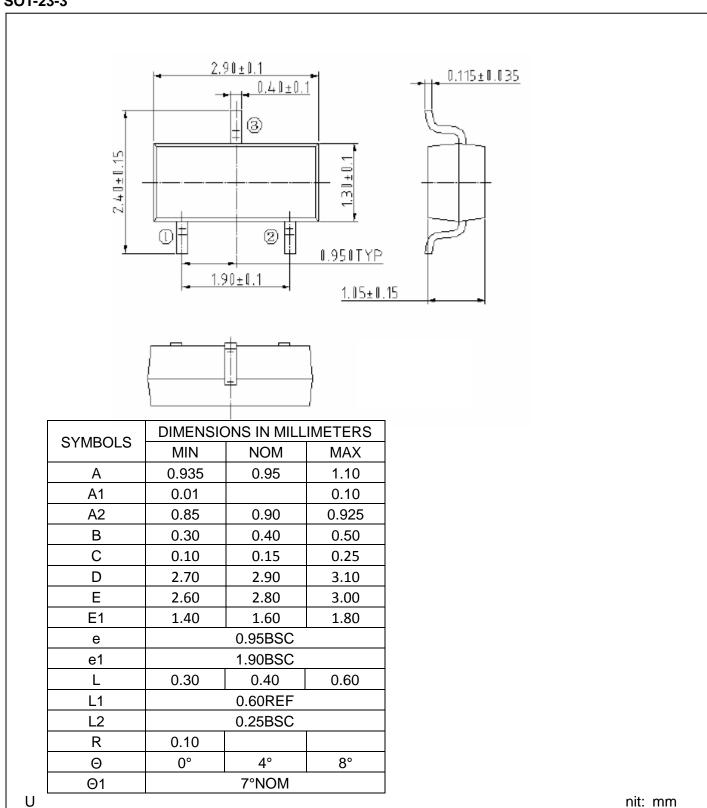
t1 TIME (sec)

11. Normalized Thermal Transient Junction to Ambient



## **Packing Information**

### **SOT-23-3**





#### Notes

ACE does not assume any responsibility for use as critical components in life support devices or systems without the express written approval of the president and general counsel of ACE Electronics Co., LTD. As sued herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and shoes failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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